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# RQK0609CQDQS

# Silicon N Channel MOS FET Power Switching

REJ03G1622-0100 Rev.1.00 Mar 03, 2008

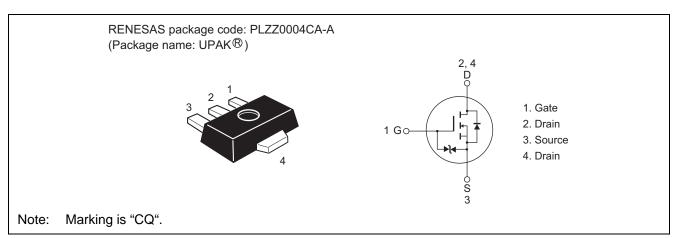
#### **Features**

• Low on-resistance

 $R_{\rm DS(on)} = 78~\text{m}\Omega$  typ.(at  $V_{GS} = 4.5~\text{V},~I_D = 2~\text{A})$ 

- Low drive current
- High speed switching
- $\bullet \quad V_{DSS}: 60~V~and~capable~of~2.5~V~gate~drive$

#### **Outline**



### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit	
Drain to source voltage	V <sub>DSS</sub>	60	V	
Gate to source voltage	$V_{GSS}$	±12	V	
Drain current	I <sub>D</sub>	4	А	
Drain peak current	I <sub>D(pulse)</sub> Note1	12	А	
Body - drain diode reverse drain current	I <sub>DR</sub>	4	А	
Channel dissipation	Pch Note2	1.5	W	
Channel temperature	Tch	150	°C	
Storage temperature	Tstg	−55 to +150	°C	

Notes: 1. PW  $\leq$  10  $\mu$ s, Duty cycle  $\leq$  1%

2. When using the glass epoxy board (FR-4  $40\times40\times1$  mm)

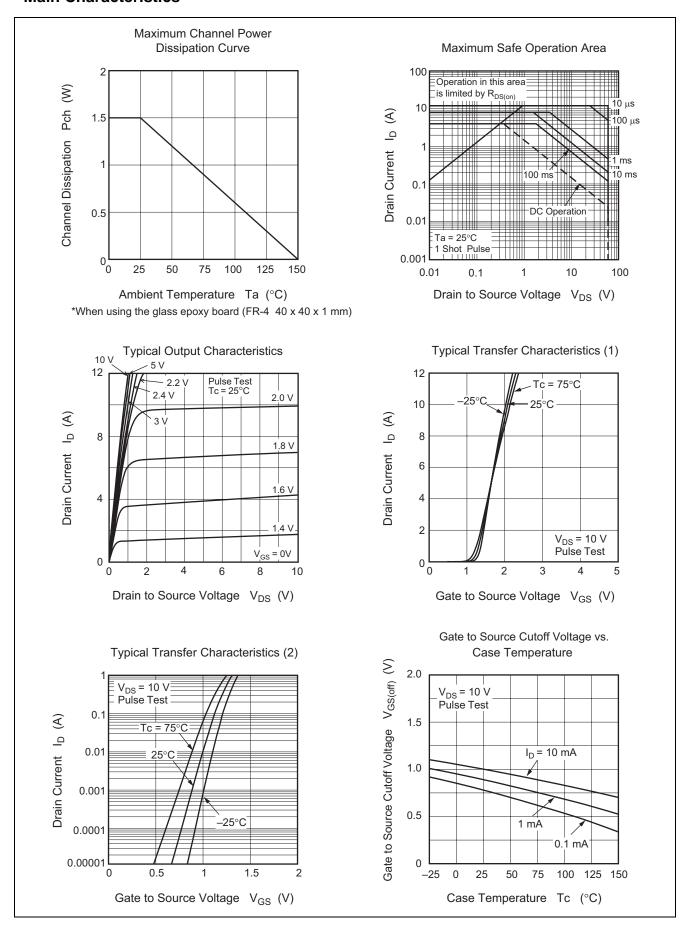
### **Electrical Characteristics**

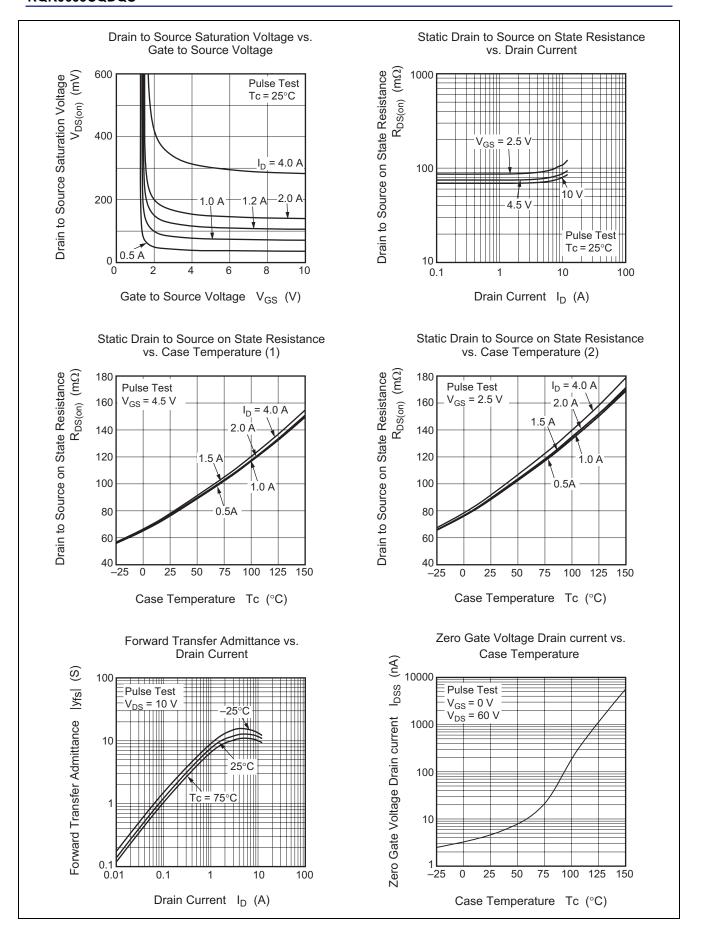
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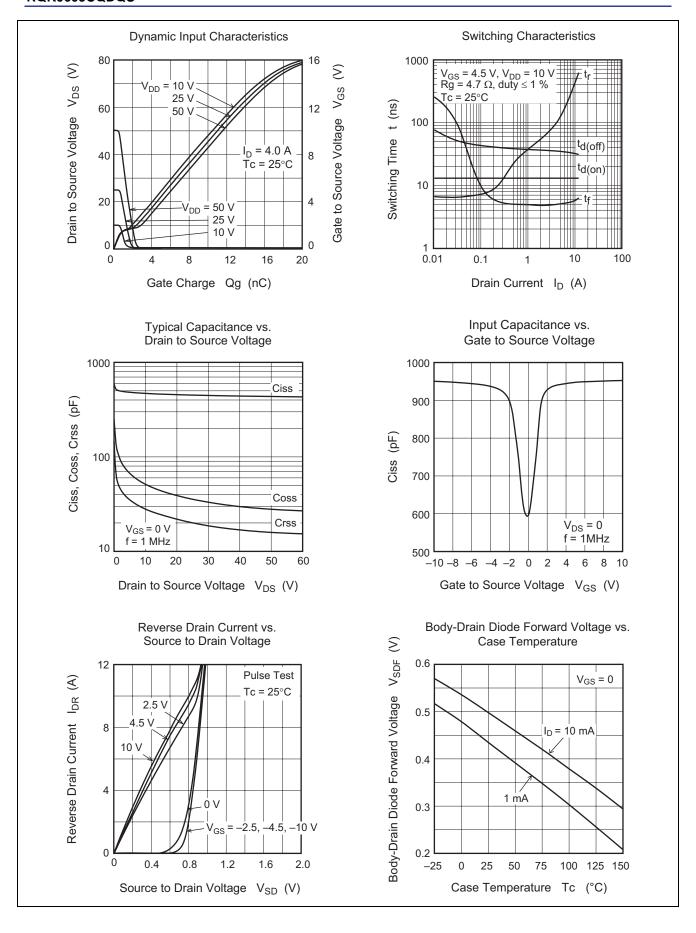
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	60	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	+12	_	_	V	$I_G = +100  \mu A,  V_{DS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	-12	_	_	V	$I_G = -100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	+10	μΑ	$V_{GS} = +10 \text{ V}, V_{DS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	-10	μΑ	$V_{GS} = -10 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 60 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	0.4	_	1.4	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Drain to source on state resistance	R <sub>DS(on)</sub>	_	78	100	mΩ	$I_D = 2 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note3}}$
Drain to source on state resistance	R <sub>DS(on)</sub>	_	90	125	mΩ	$I_D = 2 \text{ A}, V_{GS} = 2.5 \text{ V}^{\text{Note3}}$
Forward transfer admittance	y <sub>fs</sub>	7.5	12	_	S	$I_D = 2 A, V_{DS} = 10 V^{Note3}$
Input capacitance	Ciss	_	470	_	pF	V <sub>DS</sub> = 10 V
Output capacitance	Coss	_	52	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	30	_	pF	f = 1 MHz
Turn - on delay time	t <sub>d(on)</sub>	_	14	_	ns	I <sub>D</sub> = 2 A
Rise time	t <sub>r</sub>	_	56	_	ns	$V_{GS} = 4.5 \text{ V}$
Turn - off delay time	t <sub>d(off)</sub>	_	38	_	ns	$R_L = 5 \Omega$
Fall time	t <sub>f</sub>	_	5	_	ns	$Rg = 4.7 \Omega$
Total gate charge	Qg	_	5	_	nC	V <sub>DD</sub> = 10 V
Gate to Source charge	Qgs	_	0.8	_	nC	$V_{GS} = 4.5 \text{ V}$
Gate to drain charge	Qgd	_	1	_	nC	I <sub>D</sub> = 4 A
Body - drain diode forward voltage	$V_{DF}$	_	0.8	_	V	$I_F = 4 A$ , $V_{GS} = 0$ Note3

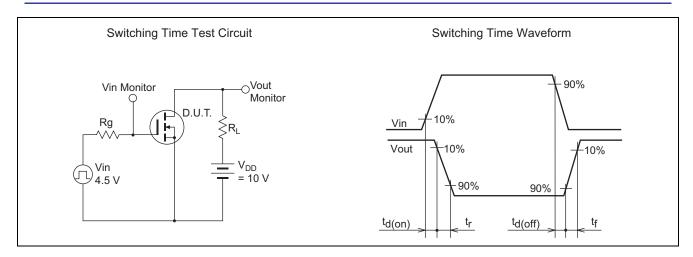
Notes: 3. Pulse test

#### **Main Characteristics**

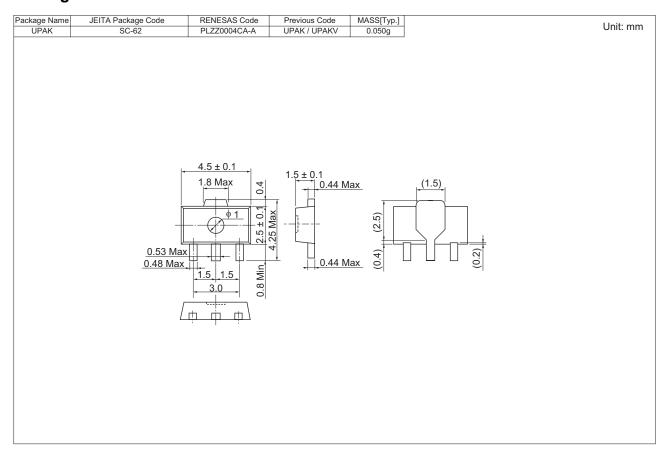








### **Package Dimensions**



### **Ordering Information**

Part No.	Quantity	Shipping Container	
RQK0609CQDQSTL-E	1000 pcs.	φ178 mm reel, 12 mm Emboss taping	

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